C. Noise in Microwave Systems

Bad News: Even if we **completely** reject the image and all spurious signals, there will still be an unwanted signal that will **always** appear at the detector/demodulator.

→ NOISE

- Q: What is noise, and where does it come from?
- A: HO: Receiver Noise
- Q: So how do we quantify noise?
- A: HO: The Statistics of Noise
- Q: How much external noise do we typically see?
- A: HO: Antenna Noise Temperature
- **Q:** What about **internal** noise; how much noise is generated by a microwave **component** in our receiver?

A: HO: Equivalent Noise Temperature

Another way to specify the noise performance of a microwave component is by its **Noise Figure**.

HO: Noise Figure and SNR

Q: What about **passive** devices; do they generate noise? What is their noise figure?

A: HO: Noise Figure of Passive Devices

A microwave system (e.g., a receiver) is made of **many components**. We can (and must!) determine the overall system noise figure and/or equivalent noise temperature for an **entire** system.

HO: System Equivalent Noise Temperature

HO: System Noise Figure

Receiver Noise

Q: Say we tune our receiver to a frequency at which **no** signal is present. Does this mean that the output of the detector/demodulator will be **zero**?

A: Nope! Unfortunately, even if we completely reject all spurious signals, there will always be one "unwanted" signal that reaches the demodulator/ detector.

→ This unwanted signal is called **noise**.

Noise is a completely random signal, and when it reaches the

demodulator the result is a completely **random** demodulator output. This provides the familiar **"hiss"** you might here if you tune your **radio** to a frequency where no station exists, or the **"snow"** you see on your **television** if you



similarly select a channel where no station exists!

Q: Big deal! I'd never tune to a frequency where there is **no** signal. Is this "noise" really a problem?

A: A big problem! Note that we said that noise will always be present at the detector/demodulator—there is no way to completely get rid of it.

As a result, the best we can hope for (if we completely suppress all spurious signals) is that only the desired signal s(t) and noise n(t) will reach the demodulator/detector.

$$\frac{s(t)+n(t)}{i(t)-i(t)+\varepsilon(t)}$$

This noise will then cause an error $\varepsilon(t)$ in the demodulated signal $\hat{i}(t)!$

Q: Yikes! How large will this error be?

A: It depends many things (e.g., modulation type, signal bandwidth, signal power), but most fundamentally it depends on the Signal-to-Noise Ratio (SNR) at the demodulator input. This ratio is simply the power associated with the signal (P_s) , to the power associated with the noise (P_n) :

$$SNR = \frac{P_s}{P_n}$$
 $SNR(dB) = P_s(dBm) - P_n(dBm)$

Thus, if there is a lot of signal power, and just a little noise power, the SNR will be large. If the converse is true, the SNR will be small.

Then—as you might expect—the demodulator error $\varepsilon(t)$ diminishes as SNR increases. Thus:

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The SNR at the demodulator input must be sufficiently large in order for demodulator error to be acceptably small.

Q: No problem! If we place enough **amplifiers** in front the demodulator/detector, then we can always make P_s **really** *large*—right?



A: Yes—but—there's one big catch. Although amplifiers of course increase signal power P_s , they increase the noise power P_n even more!

Thus, we will find that amplifiers actually decrease SNR!



This is a tremendous **challenge** for radio engineers and receiver designers. We must:

1. Increase the **signal** power (by amplification), such that the signal is large enough to be detected/demodulated.

2. But make sure that the SNR is **not** degraded to the extent that the demodulation error is **unacceptable**.

Q: From where does noise originate?

A: Two sources: one external and one internal!

External Noise

* External noise is **coupled** into the receiver through the receiver **antenna**. It turns out that the **entire** electromagnetic spectrum is awash in **random energy** (i.e., noise).

* This random energy has neither a specific **frequency**, nor **direction**, but instead is spread across **all** directions and **all** frequencies!

* As a result, we can point our antenna in **any direction**, and we can tune our receiver to **any frequency**, but we will **always** receive a portion of the electromagnetic noise!

Q: What is the source of this external noise?

A: There are three sources: terrestrial, extra terrestrial and human-made.

<u>Terrestrial Noise</u> - Every warm object radiates electromagnetic energy (its one method of heat transfer)!

Definition of warm \rightarrow Anything with a temperature **above** absolute **zero** (i.e., $> 0 K^{\circ}$).



* The frequency spectrum of this emitted electromagnetic noise depends on the **temperature** of the object.



* For objects on the Earth (i.e., terrestrial objects), the temperature is such that the emitted energy peaks in the infrared region.

* However, terrestrial objects emit random energy across the **entire** electromagnetic spectrum—including the **RF** and **microwave** regions!



<u>Extra-Terrestrial</u> - There are also very warm objects in outer space! Among these objects are of course stars and planets, but the most significant of these extraterrestrial objects is our very own star—the **Sun**! The Sun—as you **may** already know—is really **hot**. As a result it radiates electromagnetic noise at an **astonishing** rate! Some of this noise is unfortunately radiated in the **RF/microwave** end of the e.m. spectrum (a great **annoyance** to us radio engineers), but the noise power radiated by the Sun **peaks** in the **"visible region"** of the electromagnetic spectrum.



Q: Wait a second! Our eyes detect electromagnetic energy in the visible region of the e.m. spectrum. Why haven't I ever noticed this noise?

A: You have! What our eyes "see" is this noise—sunlight is in fact extra-terrestrial electromagnetic noise produced by a very hot Sun.







<u>Human-Made Noise</u> - We humans generate a heck of a lot of random noise (both electromagnetic and otherwise)! We have built literally millions of transmitters, and each of these radiate noise that was **internally** generated!

Internal Noise

Any warm object that efficiently **absorbs** electromagnetic energy must likewise **emit** electromagnetic energy (in the form of noise).

> These objects include resistors and semiconductors!

Q: Many of the components in our **receiver** have resistors and semiconductors; does this mean that **they** produce noise?

A: Absolutely! This is a **major** headache for radio engineers. Not only do we end up amplifying the **external** noise coupled into the receiver through the antenna, but the receiver itself adds to this random signal by the noise it **internally** generates!

<u>The Statistics of</u> <u>Thermal Noise</u>

Noise is a completely **random** signal. It **cannot** be described deterministically, but it can be described **statistically**.



For example, consider the **frequency spectrum** of a noise process $v_n(t)$:

$$S_n(f) = \frac{1}{2\pi} \int_{-\infty}^{\infty} v_n(t) e^{-j2\pi ft} dt$$

From this we can determine the **spectral power density** of this noise:

$$N(f) = \left|S_n(f)\right|^2 - W/Hz$$

This function describes how the **energy** of a signal is **distributed** across the **frequency spectrum**. Since noise is a

random function (i.e., a random process), its spectral power density is likewise **random**.

Thus, N(f) likewise cannot be described **deterministically**, but it **can** be described statistically. In other words, we cannot state specifically how the noise energy is distributed across the frequency spectrum, but we can describe how it is distributed—on **average**!

The function N(f) therefore is defined as the average spectral power density of noise.

Now, let's consider the average spectral power density of a **resistor** R at **temperature** T.

Q: How could a resistor produce a noise signal $v_n(t)$? Isn't a resistor a **passive** device that produces **no** power?

A: That's not quite true!

Since the resistor is a warm object, the free electrons within the device will be Rmoving (due to thermal energy) in a random way. This creates a tiny electric field I_g within the device, which in turn creates a tiny voltage across this resistor.

This voltage is the resistor noise voltage $v_n(t)$. We call this phenomenon **thermal noise**.

 $v_n(t)$

Q: What **is** the average spectral power density N(f) of this **thermal noise**?

A: Using a **bunch** quantum physics, we find that the thermal noise produced by a resistor is:

 $N(f) = kT \doteq N_0 \qquad W/_{Hz}$

where:

 \mathcal{T} is the temperature of the resistor in degrees Kelvin. and

k = Boltzman's Constant

$$= 1.38 \times 10^{-23} \quad J/_{K^{\circ}}$$

Since k is a constant, engineers often specify temperature T instead of N_0 , they call this temperature the **noise temperature**:

$$T = \frac{N_0}{k}$$

Q: Wait! This function N(f) seems to be **independent of** frequency f !?!

A: That's correct! The average spectral power density of thermal noise is theoretically a **constant** with respect to **frequency**.

 N_0^-

N(f)

f

In other words, the noise power is (on average) **distributed uniformly** across the frequency spectrum—no frequency will have any more or less (on average) than any other frequency.

→ Noise of this type is called white noise.

Q: And this function N(f) is also independent of the value of **resistance** R !?!

A: That is again correct! The noise that a resistor produces does **not** depend on its resistance, it depends **only** on its temperature. However, this "resistor" **cannot** have the values R = 0 or $R = \infty$ —it **must** be able to absorb power.

Q: So $N(f) = N_0$ is the average spectral power density of the thermal noise. What simply is the **total power** P_n of the thermal noise?

A: We can determine the total power from the average spectral power density by **integrating** the power density over all frequency:

$$P_n = \int_0^\infty N(f) df$$

Q: Yikes! If we integrate $N(f) = N_0$ over all frequency, we get **infinite** power!

$$P_n = \int_0^\infty N_0 df = \infty$$
 ??? (Is the energy crisis solved?)

A: The reality is, as frequency gets extremely large, we find that the average spectral power density will diminish to zero.

$$\lim N(f) = 0$$

In other words, the result:

$$N(f) = kT$$

is an **approximation** that is valid in the R**F/microwave region** of the electromagnetic spectrum.

Therefore:

$$P_n = \int_{\Omega}^{\infty} N(f) \, df < \infty$$

Q: Still, wouldn't the resulting value of P_n still be quite large?

A: Mathematically speaking, yes.

But remember, resistors reside in circuits with **reactive** elements. As a result, every microwave device has a **finite bandwidth**. This finite bandwidth will **limit** the amount of noise power that passes through the receiver to the demodulator.

For example, consider the case where a **bandpass filter** is connected between two resistors:







We'll consider the resistor on the **left** to be **source** of thermal noise, with average spectral power density:

$$N_{in}(f) = N_0$$

While the resistor on the **right** is a **load** that absorbs noise power P_n^{out} .

The bandpass filter has a power **transmission** coefficient T(f), where:

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 R_{l}



Thus, the average spectral power density of the noise at the load is:

$$N_{out}(f) = N_{in}(f) \mathbf{T}(f) = N_0 \mathbf{T}(f)$$

And we conclude:

$$N_{out}(f) \approx \begin{cases} N_0 & \text{for } f \text{ in filter passband} \\ 0.0 & \text{for } f \text{ in filter stopband} \end{cases}$$

$$N(f) \quad T(f) \quad N_0 \quad f \text{ in filter stopband} \quad f \text{ in filter stopband} \end{cases}$$

f

Now, if the filter has a **passband** that extends from frequency f_1 to frequency f_2 (i.e., bandwidth $B = f_2 - f_1$), the **total power** of the noise at the **load** is:

$$P_n^{out} = \int_0^\infty \mathcal{N}_0 \mathbf{T}(f) df$$
$$= \mathcal{N}_0 \int_0^\infty \mathbf{T}(f) df$$
$$\simeq \mathcal{N}_0 \int_{f_1}^{f_2} 1.0 df$$
$$= \mathcal{N}_0 \mathcal{B}$$

Thus, we can conclude that the **thermal noise** produced by some resistor R at temperature T, when constrained to some finite bandwidth B (and it **always** is constrained in this way!), has **total power**:

$$P_n = kTB = N_0B$$

<u>Antenna Noise</u>

Temperature

Q: So, **external** noise will be coupled into our receiver through the receiver **antenna**. What will the average spectral power density of this noise be?

Rx



A: Generally speaking, it will be white noise!

In other words, the average spectral power density of the externally generated noise will be **constant** with respect to frequency (or at least, constant across the **antenna bandwidth**).

Thus, as far as noise (and only noise) is concerned, the receiver appears to have a **warm resistor** attached to its input!

N₄

Rx

We can specify this input noise in terms of average spectral power density N_A , but we **typically** define it in terms of its **noise temperature**:

$$T_{\mathcal{A}} \doteq \frac{N_{\mathcal{A}}}{k} \qquad K^{\circ}$$

We call T_A the antenna noise temperature—it's the apparent temperature of the warm resistor "attached" to the receiver input.

Thus, we can write:

$$N_{A} = k T_{A}$$

Q: Is there some typical value of antenna temperature?

A: It depends on which direction the antenna is pointing!

 $T_{A} < 10 K$

* If the antenna is pointed toward the **sky** (e.g., satellite communications), the antenna noise temperature could be very **low**, on the order of 10 K° or less. The one big **exception** to this occurs when you point your antenna at the **Sun**.



* If the antenna is **not** pointed at the sky, then most of the external noise will be generated by **terrestrial** sources. It turns out that the antenna noise temperature in this case is simply equal to the **physical temperature** at the Earth's surface!

Of course, this temperature changes somewhat, but expressed in degrees **Kelvin** (i.e., with respect to **absolute** zero) this change is **small**.

Thus, radio engineers typically assume an antenna noise temperature of a standard value of $T_o = 290 K^\circ$.

 $T \approx 290 K$



Equivalent Noise

Temperature

In addition to the **external** noise coupled into the receiver through the antenna, each **component** of a receiver generates its own **internal** noise!

For example, consider an **amplifier** with gain G and bandwidth B:

$$V_{in} \rightarrow G \qquad P_n^{out} = B N_{out}$$

Here there is no input signal at the amplifier input, other than some white (i.e., uniform across the RF and microwave spectrum) noise with average spectral power density N_{in} . At the **output** of the amplifier is likewise noise, with an average spectral power density of N_{out} .

This **output** average spectral power density N_{out} is typically **not** wideband, but instead is uniform only over the **bandwidth** of the amplifier:

$$\left[N_{out} \right]$$
 for f in bandwidth B

 $N(f) \approx \begin{cases} \\ \ll N_{out} & \text{for } f \text{ outside bandwidth } B \end{cases}$



Q: Yikes! Does an amplifier **somehow** amplify noise **more** than it amplifies **other** input signals?

A: Actually, the amplifier **cannot** tell the difference between input noise and any other input signal. It **does** amplify the input noise, increasing its magnitude by gain *G*.

Q: But you **just** said that $N_{out} \gg G N_{in}$!?!

A: This is true! The reason that $N_{out} \gg G N_{in}$ is because the amplifier additionally generates and outputs its own noise signal! This internally generated amplifier noise has an average spectral power density (at the output) of N_n .

Thus, the output noise N_{out} consists of **two** parts: the **first** is the noise at the **input** that is amplified by a factor G (i.e., GN_{in}), and the **second** is the noise generated **internally** by the amplifier (i.e., N_n).

Since these two noise sources are **independent**, the average spectral power density at the output is simply the **sum** of each of the two components:

$$N_{out} = G N_{in} + N_n$$

Q: So does this noise generated **internally** in the amplifier actually get **amplified** (with a gain G) or not?

A: The internal amplifier noise is generated by every resistor and semiconductor element throughout the amplifier. Some of the noise undoubtedly is generated near the input and thus amplified, other noise is undoubtedly generated near the output and thus is not amplified at all, while still more noise might be generated somewhere in the middle and thus only partially amplified (e.g., by 0.35 G).

However, it does not matter, as the value N_n does not specify the value of the noise power generated at any point within the amplifier. Rather it specifies the **total** value of the noise generated throughout the amplifier, as this total noise **exits the amplifier output**.

As a result, we can **model** a "noisy" amplifier (and they're **all** noisy!) as an **noiseless** amplifier, followed by an output **noise source** producing an average spectral power density N_n :



Nin

Noise Source

w/ average

SPD N, G

Note however that this is **not** the **only** way we can model internally generated noise. We could **alternatively** assume that **all** the internally generated noise occurs near the amplifier **input**—and thus **all** this noise is amplified with gain *G*.

G

Amplifier

Note here that the noise source near the **input** of the amplifier has an average spectral power density of N_n/G .

It is in fact **this** model (where the internal noise is assumed to be created by the input) that we more **typically** use when considering the internal noise of an amplifier!

To see **why**, recall that we can alternatively express the average SPD of noise in terms of a **noise temperature** T(in degrees Kelvin):

$$N = kT$$

 $N_{out} = G(N_{in} + N_n/G)$

 $= G N_{in} + N_n$

Ideal

Noiseless

Amplifier

w/ gain G

Thus, we can express the input noise in terms of an **input noise temperature**:

$$N_{in} = k T_{in} \implies T_{in} \doteq N_{in}/k$$

or the output noise temperature as:

$$N_{out} = kT_{out} \implies T_{out} \doteq N_{out}/k$$

Similarly, we can describe the **internal** amplifier noise, when modeled as being generated near the amplifier **input**, as:

$$\frac{N_n}{G} = kT_e$$

Where noise temperature T_e is defined as the equivalent (input) noise temperature of the amplifier:

$$T_e \doteq \frac{N_n}{kG}$$

Note this equivalent noise temperature is a **device parameter** (just like gain!)—it tells us how noisy our amplifier is.

Of course, the **lower** the equivalent noise temperature, the **better**. For example, an amplifier with $T_e = 0 K^\circ$ would produce **no** internal noise at all!



Noise Figure and SNR

Of course, in addition to noise, the input to an amplifier in a receiver will typically include our desired **signal**.

Say the **power** of this input signal is P_s^{in} . The output of the amplifier will therefore include **both** a signal with power P_s^{out} , and noise with power P_n^{out} :



where:

and:

$$P_n^{out} = N_{in} + G k T_e B$$
$$= G k (T_{in} + T_e) B$$

In order to accurately demodulate the signal, it is important that signal power be **large** in comparison to the noise power. Thus, a fundamental and important measure in radio systems is the **Signal-to-Noise Ratio** (SNR):

$$SNR \doteq \frac{P_s}{P_n}$$

The larger the SNR, the better!

At the **output** of the amplifier, the SNR is:

$$SNR_{out} = \frac{P_s^{out}}{P_n^{out}}$$
$$= \frac{G P_s^{in}}{G k (T_{in} + T_e) B}$$
$$= \frac{P_s^{in}}{k (T_{in} + T_e) B}$$

Moreover, we can define an **input noise power** as the total noise power across the **bandwidth of the amplifier**:

$$P_n^{in} = N_{in} B = k T_{in} B$$

And thus the input SNR as:

$$SNR_{in} = \frac{P_s^{in}}{P_n^{in}} = \frac{P_s^{in}}{kT_{in}B}$$

Now, let's take the **ratio** of the input SNR to the output SNR:

$$\frac{SNR_{in}}{SNR_{out}} = \frac{P_s^{in}}{kT_{in}B} \left(\frac{k(T_{in} + T_e)B}{P_s^{in}} \right)$$
$$= \frac{T_{in} + T_e}{T_{in}}$$
$$= 1 + \frac{T_e}{T_{in}}$$

Since $T_e > 0$, it is evident that:

$$\frac{SNR_{in}}{SNR_{out}} = 1 + \frac{T_e}{T_{in}} > 1$$

In other words, the SNR at the **output** of the amplifier will be **less** than the SNR at the **input**.

> This is very **bad** news!

This result means that the SNR will always be **degraded** as the signal passes through **any** microwave component!

As a result, the SNR at the **input** of a receiver will be the largest value it will **ever** be within the receiver. As the signal passes through each component of the receiver, the SNR will get steadily **worse**!

Q: Why is that? After all, if we have several amplifiers in our receiver, the **signal** power will significantly **increase**?

A: True! But remember, this gain will likewise increase the receiver input **noise** by the **same** amount. Moreover, each component will add **even more noise**—the internal noise produced by each receiver component.

Thus, the power of a signal traveling through a receiver increases—but the **noise** power increases **even more**!

Note that the ratio *SNR_{in}*/*SNR_{out}* essentially quantifies the degradation of SNR by an amplifier—a ratio of **one** is **ideal**, a **large** ratio is very **bad**.

So, let's go back and look again at ratio SNR_{in}/SNR_{out}:

$$\frac{SNR_{in}}{SNR_{out}} = 1 + \frac{T_e}{T_{in}}$$

Note what this ratio depends on, and what it does not.

This ratio depends on:

1. T_e (a device parameter)

2. T_{in} (not a device parameter)

This ratio does not depend on:

1. The amplifier gain G.

2. The amplifier bandwidth B.

We thus might be tempted to use the ratio SNR_{in}/SNR_{out} as another **device parameter** for describing the **noise** performance of an amplifier. After all, SNR_{in}/SNR_{out} depends on T_e , but does **not** depend on other device parameters such as *G* or *B*.

Moreover, SNR is a value that can generally be easily **measured**!

But the problem is the **input** noise temperature T_{in} . This can be **any** value—it is **independent** of the amplifier itself.

For **example**, it is event that as the input noise increases to **infinity**:

$$\lim_{T_{in}\to\infty}\frac{SNR_{in}}{SNR_{out}} = \lim_{T_{in}\to\infty}\left(1+\frac{T_e}{T_{in}}\right) = 1$$

In other words, if the input noise is large enough, the internally generated amplifier noise will become **insignificant**, and thus will degrade the SNR **very little**!

Q: Degrade the SNR very little! This means SNR_{out} = SNR_{in}! Isn't this **desirable**?

A: Not in this instance. Note that if T_{in} increases to infinity, then:

$$\lim_{T_{in}\to\infty} SNR_{in} = \lim_{T_{in}\to\infty} \left(\frac{P_s^{in}}{kT_{in}B} \right) = 0$$

In other words, the SNR does is not degraded by the amplifier **only** because the SNR is already as bad (i.e., SNR = 0) as it can possibly get!

Conversely, as the input noise temperature decreases toward **zero**, we find:

$$\lim_{T_{in}\to 0}\frac{SNR_{in}}{SNR_{out}} = \lim_{T_{in}\to 0}\left(1+\frac{T_e}{T_{in}}\right) = \infty$$

Q: Yikes! The amplifier degrades the SNR by an infinite percentage! Isn't this **undesirable**?

A: Not in this instance. Note that if T_{in} decreases to zero, then:

$$\lim_{T_{in}\to 0} SNR_{in} = \lim_{T_{in}\to 0} \left(\frac{P_s^{\prime n}}{k T_{in} B} \right) = \infty$$

Note this is the **perfect** SNR, and thus the ratio SNR_{in}/SNR_{out} will likewise be infinity, **regardless** of the amplifier.

Anyway, the **point** here is that although the degradation of *SNR* by the amplifier does depend on the **amplifier** noise characteristics (i.e., T_e), it **also** on the noise input to the amplifier (i.e., T_{in}).

This input noise is a variable that is unrelated to amplifier performace

Q: So there is no way to use SNR_{in}/SNR_{out} as a device

parameter?

A: Actually there is! In fact, it is the most prevalent parameter for specifying microwave device noise performance. This measure is called **noise figure**.

The noise figure of a device is simply the measured ratio SNR_{in}/SNR_{out} exhibited by a device, for a specific input noise temperature T_{in} .

I repeat:

$$\rightarrow$$
 "for a specific input noise temperature \mathcal{T}_{in} ."

This specific noise temperature is almost **always** taken as the standard "room temperature" of $T_o = 290 K^\circ$. Note this was likewise the standard **antenna noise temperature** assumption.

Thus, the Noise Figure (F) of a device is defined as:

$$F \doteq \frac{SNR_{in}}{SNR_{out}} \bigg|_{T_{in}=290K^{\circ}}$$
$$= \left(1 + \frac{T_e}{T_{in}}\right) \bigg|_{T_{in}=290K^{\circ}}$$
$$= 1 + \frac{T_e}{290K^{\circ}}$$



It is critically important that **you** understand the **definition** of noise figure. A common **mistake** is to assume that:

$$SNR_{out} = \frac{SNR_{in}}{F} \leftarrow This is not generally true!$$

Note this would only be true if $T_{in} = 290K^{\circ}$, but this is almost **never** the case (i.e., $T_{in} \neq 290K^{\circ}$ generally speaking).

Thus, an incorrect (but widely repeated) statement would be:

" The noise figure specifies the degradation of SNR."

Whereas, a **correct** statement is:



" The noise figure specifies the degradation of SNR, for the specific condition when T_{in} = 290K°, and for that specific condition **only**"

The one **exception** to this is when an **antenna** is connected to the input of an amplifier. For this case, it is evident that the input temperature is $T_A = T_{in} = 290K^\circ$:

$$T_{in} = T_A = 290K^{\circ}$$

$$SNR_{out} = SNR_{in}/F$$

Note that since the noise figure F of a given device is dependent on its equivalent noise temperature T_e , we can **determine** the equivalent noise temperature T_e of a device with knowledge F:

$$F = 1 + \frac{T_e}{290K^\circ}$$
 \Leftrightarrow $T_e = (F-1)290K^\circ$

One **more** point. Note that noise figure *F* is a **unitless** value (just like gain!). As such, we can easily express it in terms of **decibels** (just like gain!):

$$F(dB) = 10 \log_{10} F$$

Like gain, the noise figure of an amplifier is **typically** expressed in *dB*.

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<u>Noise Figure of</u> <u>Passive Devices</u>

Recall that passive devices are typically lossy. Thus, they have a "gain" that is less than one—we can define this in terms of device attenuation A:

$$A = \frac{1}{G}$$

where for a lossy, passive device G < 1, therefore A > 1.

Q: What is the equivalent noise temperature T_e or noise figure F of a **passive** device (i.e., **not** an amplifier)?

A: The equivalent noise temperature of a passive device can be shown to be approximately (trust me!):

 $T_e = (A - 1)T$

where T is the **physical** temperature of the passive device. Typically we assume this physical temperature to be 290 K° , so that:

$$T_e = (A-1) 290K^{\circ}$$



$$T_{out} = \mathcal{G}\left(T_{in} + T_{e}\right)$$
$$= \frac{T_{in} + T_{e}}{A}$$
$$= \frac{T_{in}}{A} + \frac{(A - 1)290 \, K^{\circ}}{A}$$
$$= \frac{T_{in}}{A} - \frac{290 \, K^{\circ}}{A} + 290 \, K^{\circ}$$

This result is very interesting, and makes sense physically. As attenuation A approaches the lossless case A = 1, we find that $T_{out} = T_{in}$. In other words the noise passes through the device unattneuated, and the device produces no internal noise!

→ Just like a length of lossless transmission line!

On the other hand, as A gets very large, the input noise is completely absorbed by the device. The noise at the device output is entirely generated internally, with a noise temperature $T_{out} = 290 K^{\circ}$ equal to its physical temperature. → Just like the output of a **resistor** at physical temperature $T = 290 K^{\circ}$

Q: So, what is the **noise figure** F of a **passive** device?

Now, we determined earlier that the **noise figure** of a twoport device is related to its equivalent noise temperature as:

$$F = 1 + \frac{I_e}{290 \, K^o}$$

Therefore, the noise figure of a **passive** device is:

$$F = 1 + \frac{(A-1)290K^{\circ}}{290K^{\circ}}$$
$$= 1 + (A-1)$$
$$= A$$

Thus, for a **passive** device, the noise figure is **equal** to its attenuation!

$$F = 1/G = A$$

So, for an **active** two-port device (e.g., an amplifier), we find that two important and **independent device parameters** are gain G and noise figure F—both values must be specified.

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However, for **passive** two-port devices (e.g., an attenuator), we find that attenuation *A* and noise figure *F* are not only completely **dependent**—they are in fact **equal**!

Finally, we should not that the value *A* represents the attenuation (i.e., loss) of **any** passive device—**not** just an attenuator.

For example, *A* would equal the **insertion loss** for a switch, filter, or coupler. Likewise, it would equal the **conversion loss** of a mixer.

Thus, **you** should now be able to specify the noise figure and equivalent noise temperature of each and **every** two-port device that we have studied!

<u>System Equivalent</u> <u>Noise Temperature</u>

Say we **cascade** three microwave devices, each with a different **gain** and **equivalent noise temperature**:



These three devices together can be thought of as **one** new microwave device.

Q: What is the equivalent noise temperature T_e of this **overall** device?

A: First of all, we must define this temperature as the value T_e such that:

$$T_{out} = G(T_{in} + T_e)$$

or specifically:

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 $T_e = \frac{T_{out}}{G} - T_{in}$

Q: Yikes! What is the value of G?

A: The value G is the **total system gain**; in other words, the overall gain of the three cascaded devices. This gain is particularly easy to determine, as is it simply the **product** of the three gains:

$$G = G_1 G_2 G_3$$

Now for the hard part! To determine the value of T_{out} , we must use our equivalent noise model that we studied earlier:





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Now, since $T_{out} = T_{out3}$, we can determine the **overall** (i.e., system) equivalent noise temperature T_e :

$$T_{e} = \frac{T_{out}}{G} - T_{in}$$

$$= \frac{G_{1}G_{2}G_{3}(T_{in} + T_{e1}) + G_{2}G_{3}(T_{e2}) + G_{3}(T_{e3})}{G_{1}G_{2}G_{3}} - T_{in}$$

$$= T_{e1} + \frac{T_{e2}}{G_{1}} + \frac{T_{e3}}{G_{1}G_{2}}$$

Moreover, we will find if we cascade an N number of devices, the overall noise equivalent temperature will be:

$$T_e = T_{e1} + \frac{T_{e2}}{G_1} + \frac{T_{e3}}{G_1G_2} + \frac{T_{e4}}{G_1G_2G_3} + \dots + \frac{T_{eN}}{G_1G_2G_3\dots G_{N-1}}$$

I assume that you can use the above equation to get the correct answer—but I want to know if you understand **why** your answer is correct!

Make sure **you** understand where this expression comes from, and what it means.

Look closely at the above expression, for it tells us something very **profound** about the noise in a complex microwave system (like a receiver!). Recall that we want the equivalent noise temperature to be as **small** as possible. Now, look at the equation above, **which** terms in this summation are likely to be the **largest**?

* Assuming this system has large gain *G*, we will find that the **first** few terms of this summation will **typically dominate** the answer.

* Thus, it is evident that to make T_e as small as possible, we should start by making the **first term** as small as possible. Our **only** option is to simply make T_{e1} as small as we can.

* To make the second term small, we could likewise make T_{e^2} small, but we have another option!

 \rightarrow We could likewise make gain G_1 large!

Note that making G_1 large has **additional** benefits, as it likewise helps minimize **all** the other terms in the series!

Thus, good receiver designers are particularly careful about placing the proper component at the **beginning** of a receiver. They **covet** a device that has **high gain** but **low equivalent noise temperature** (or noise figure).

→ The ideal first device for a receiver is a low-noise amplifier!

 $G \rightarrow Biq$

 $T_e \rightarrow Small$

Q: Why **don't** the devices at the **end** of the system make much of a difference when it comes to noise?

A: Recall that each microwave device **adds** more noise to the system, As a result, noise will generally **steadily increase** as it moves through the system.

* By the time it reaches the end, the noise power is typically so large that the additional noise generated by the devices there are insignificant and make little increase in the overall noise level.

* Conversely, the noise generated by the **first** device is amplified by **every** device in the overall system—this first device thus typically has the **greatest** impact on system noise temperature and system noise figure.

System Noise Figure

Say we **again** cascade three microwave devices, each with a different **gain** and **noise figure**:



These three devices together can be thought of as **one** new microwave device.

Q: What is the noise temperature of this overall device?

A: Recall that we found the overall equivalent noise temperature of this system to be:

$$T_e = T_{e1} + \frac{T_{e2}}{G_1} + \frac{T_{e3}}{G_1 G_2}$$

Likewise, the equivalent noise temperature of each device is related to its **noise figure** as:

$$T_e = (F-1)290K^{\circ}$$

Combining these two expressions we find:

$$(F-1)290K^{\circ} = (F_1-1)290K^{\circ} + \frac{(F_2-1)290K^{\circ}}{G_1} + \frac{(F_3-1)290K^{\circ}}{G_1G_2}$$

and thus solving for F:

$$F = \frac{1}{290K^{\circ}} \left((F_1 - 1)290K^{\circ} + \frac{(F_2 - 1)290K^{\circ}}{G_1} + \frac{(F_3 - 1)290K^{\circ}}{G_1G_2} \right) + \frac{F_1 - 1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1G_2} + 1}{G_1G_2} + 1$$

$$= F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1G_2}$$

Therefore, the **overall** noise figure for the "device" consisting of three cascade amplifiers can be determined **solely** from the knowledge of the gain and noise figure of **each** individual amplifier!

$$F = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 G_2}$$

Moreover, we find that if we construct a system of N cascaded microwave components, then the **overall noise** figure of the system can be determined as:

$$\mathcal{F} = \mathcal{F}_1 + \frac{\mathcal{F}_2 - 1}{\mathcal{G}_1} + \frac{\mathcal{F}_3 - 1}{\mathcal{G}_1 \mathcal{G}_2} + \frac{\mathcal{F}_4 - 1}{\mathcal{G}_1 \mathcal{G}_2 \mathcal{G}_3} + \dots + \frac{\mathcal{F}_N - 1}{\mathcal{G}_1 \mathcal{G}_2 \mathcal{G}_3 \cdots \mathcal{G}_{N-1}}$$

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* It is again evident from inspection of this equation that the first device in the cascaded chain will likely by the most significant device in terms of the overall system noise figure.

* We come to the same conclusion as for T_e —make the first device one with low internal noise (small noise figure F_1) and high gain G.

* In other words, make the **first** device in your receiver a **Low-Noise Amplifier (LNA)**!

One other very important note:

Although we used **only** amplifiers in our examples for system equivalent noise temperature and system noise figure, the results are likewise valid for **passive** devices!

Just remember, the gain G of a passive device is simply the inverse of its attenuation A:

$G=rac{1}{A}$

Now, let's examine one important system made up of cascaded microwave components—a **receiver**!

At the **input** of every receiver is an **antenna**. This antenna, among other signals, delivers **noise power** to the input, with a temperature that is typically $T_A = 290K^\circ$.



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$$\mathcal{N}_{out} = \mathcal{K}\mathcal{T}_{out}$$

= $\mathcal{K}\mathcal{G}\mathcal{F}\left(290\mathcal{K}^{\circ}
ight)$

while the output noise power is:

$$P_n^{out} = N_{out}B$$
$$= kGF(290K^{\circ})B$$

Now, compare these values to their respective **input** values:

$$T_{in} = T_A = 290 K^{\circ}$$

$$N_{in} = k(290K^{\circ})$$

$$P_n^{in} = k(290K^\circ)B$$

Note for each of the values, the output is a factor GF greater than the input:

$$\frac{T_{out}}{T_{in}} = \frac{N_{out}}{N_{in}} = \frac{P_n^{out}}{P_n^{in}} = GF$$

However, I again emphasize, this expression is only valid if T_{in} = 290 K°!!

Of course, the ratio of the **signal** output power to the **signal** input power is: $\frac{P_s^{out}}{P_s^{in}} = G$ Thus, the **signal** power is increased by a **factor** *G*, while the **noise** power is increased by a **factor** *GF*. This is why there is reduction in SNR by a **factor** *F*!